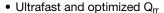


FRED Pt® Gen 5, Ultrafast Rectifier Diode, 600 V, 240 A



PRIMARY CHARACTERISTICS					
I _{F(AV)} at 95 °C (per module)	240 A				
V_{R}	600 V				
Q _{rr} (typical)	260 nC				
t _{rr}	52 ns				
Туре	Modules - diode, FRED Pt®				
Package	TO-244				
Circuit configuration	Two diodes common cathode				

FEATURES





- Best in class forward voltage drop and switching losses trade off
- RoHS
- Optimized for high speed operation
- 175 °C maximum operation junction temperature
- UL approved file E222165
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses the FRED Pt® Gen 5 is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters.

These devices are also ideally suited for HF welding, power converters, and other applications where switching losses are significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_R		600	V
		T _C = 25 °C	229	
Continuous forward current per diode	I _{F(DC)}	T _C = 85 °C	160	•
		T _C = 115 °C	120	Α
Non-repetitive single pulse forward current per diode	I _{FSM}	T _C = 25 °C	1300	
Maximum power dissipation per diode	P _D	T _C = 25 °C	395	W
Maximum power dissipation per diode		T _C = 115 °C	158	VV
Storage temperature range	T _{Stg}		-40 to +150	°C
Operating junction temperature range	TJ		-40 to +175	°C

ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. MAX.		MAX.	UNITS	
Breakdown voltage	V_{BR}	I _R = 200 μA	600	-	-	
Forward voltage	V _{FM}	I _F = 120 A	-	1.52	1.68	V
		I _F = 240 A	-	1.67	1.96	
		I _F = 120 A, T _J = 150 °C	-	1.17	-	
		I _F = 240 A, T _J = 150 °C	-	1.46	-	
Reverse leakage current	I _{RM}	T _J = 150 °C, V _R = 600 V	-	0.18	0.5	mA
Series inductance	L _S	From top of terminal hole to mounting plane	-	5	-	nH
Maximum junction capacitance per leg	C _T	V _{DC} = 5 V, f = 1 MHz, 25 °C	-	-	0.7	nF

Revision: 08-Feb-2022 1 Document Number: 96922



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	+	T _J = 25 °C		-	52	-	20
neverse recovery time	se recovery time t _{rr}	T _J = 125 °C	$I_F = 50 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 300 \text{ V}$	-	135	-	ns
Dook was a year our want	eak recovery current I _{RRM}	T _J = 25 °C		-	4.0	-	A
Peak recovery current		T _J = 125 °C		-	11.0	-	
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	260	-	nC
	Q _{rr}	T _J = 125 °C		-	1530	-	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS
Thermal resistance,	per leg	В	-	-	0.38	
junction to case	per module	R_{thJC}	-	-	0.19	°C/W
Thermal resistance, case to heatsink		R _{thCS}	-	0.10	-	
Weight			-	68	-	g
			-	2.4	-	OZ.
Mounting torque Mounting torque center hole Terminal torque			30 (3.4)	-	40 (4.6)	
			12 (1.4)	-	18 (2.1)	lbf · in (N · m)
			30 (3.4)	-	40 (4.6)] ((\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Vertical pull 2" lever pull			=	-	80	lbf ⋅ in
			=	=	35	ווויוטו
Case style			TO-244			

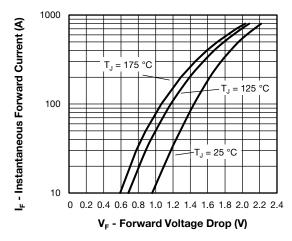
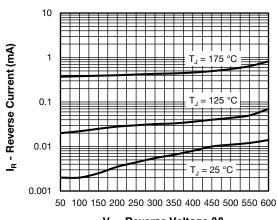


Fig. 1 - Typical Forward Voltage Drop vs. Instantaneous Forward Current (Per Diode)



V_R - Reverse Voltage (V)

Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Diode)



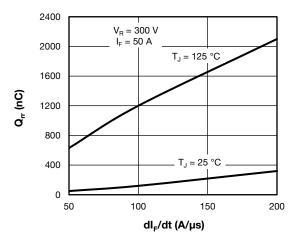


Fig. 3 - Typical Reverse Recovery Charge vs dl_F/dt (Per Diode)

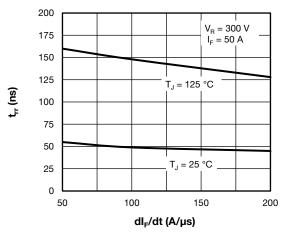


Fig. 4 - Typical Reverse Recovery Time vs dl_F/dt (Per Diode)

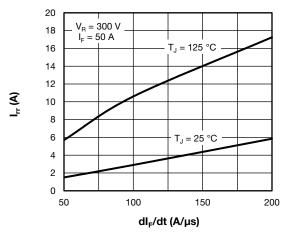


Fig. 5 - Typical Reverse Recovery Current vs dl_F/dt (Per Diode)

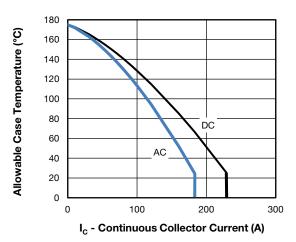


Fig. 6 - Maximum Continuous Forward Current vs.

Case Temperature

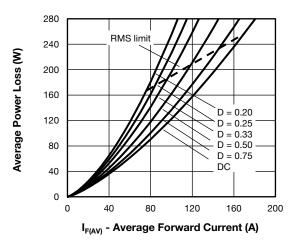


Fig. 7 - Average Power Loss vs. Average Forward Current (Forward Power Loss Characteristics)

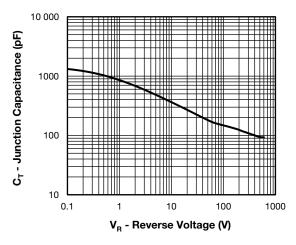


Fig. 8 - Typical Junction Capacitance vs. Reverse Voltage

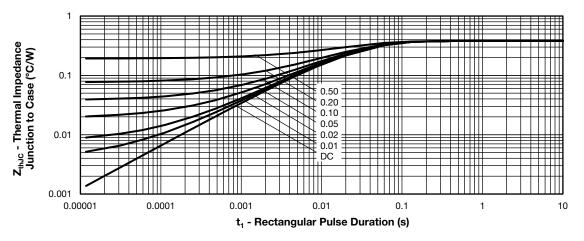
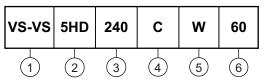


Fig. 9 - Z_{thJC} Maximum Thermal Impedance Junction to Case vs. t₁ Rectangular Pulse Duration

ORDERING INFORMATION TABLE

Device code



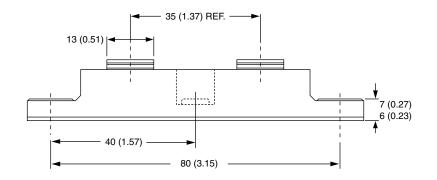
- 1 Vishay Semiconductors product
- 2 5HD = high speed FRED Pt® Gen 5
- 3 Current rating (240 = 240 A)
- 4 Circuit configuration:
 - C = two diodes common cathode
- 5 W = TO-244 wire bondable not isolated
- 6 Voltage rating (60 = 600 V)

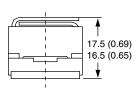
CIRCUIT CONFIGURATION				
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING		
Two diodes common cathode	С	Lug Lug terminal terminal anode 1 anode 2 Base common cathode		

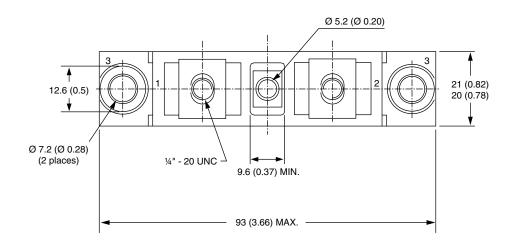
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95021		



DIMENSIONS in millimeters (inches)









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